Dual non-inverting Schmitt trigger

Rev. 1 — 22 May 2013

Product data sheet

1. General description

The 74HC2G17-Q100; 74HCT2G17-Q100 are dual buffers with Schmitt-trigger inputs. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} . Schmitt trigger inputs transform slowly changing input signals into sharply defined jitter-free output signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Input levels:
 - For 74HC2G17-Q100: CMOS level
 - For 74HCT2G17-Q100: TTL level
- Complies with JEDEC standard no. 7A
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times
- Multiple package options

3. Applications

- Wave and pulse shaper for highly noisy environments
- Astable multivibrators
- Monostable multivibrators



Dual non-inverting Schmitt trigger

4. Ordering information

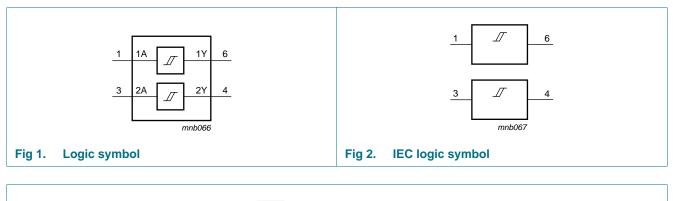
Table 1. Ordering information								
Type number	Package							
	Temperature range	Name	Description	Version				
74HC2G17GW-Q100	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74HC2G17GV-Q100	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457				
74HCT2G17GW-Q100	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363				
74HCT2G17GV-Q100	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457				

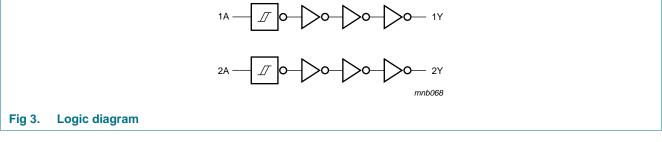
5. Marking

Table 2. Marking	
Type number	Marking code ^[1]
74HC2G17GW-Q100	HV
74HC2G17GV-Q100	HV
74HCT2G17GW-Q100	TV
74HCT2G17GV-Q100	TV

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



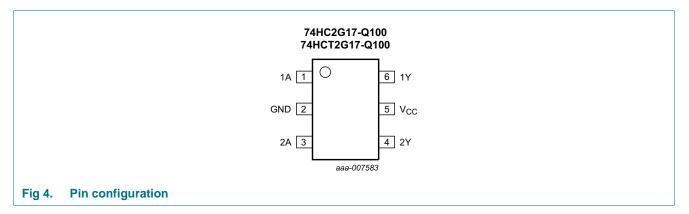


74HC_HCT2G17_Q100

Dual non-inverting Schmitt trigger

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3.	Pin description	
Symbol	Pin	Description
1A	1	data input
GND	2	ground (0 V)
2A	3	data input
2Y	4	data output
V _{CC}	5	supply voltage
1Y	6	data output

8. Functional description

Table 4.	Function table ^[1]	
Input		Output
nA		nY
L		L
Н		Н

[1] H = HIGH voltage level;

L = LOW voltage level.

Dual non-inverting Schmitt trigger

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7.0	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{CC} + 0.5 V	<u>[1]</u> _	±20	mA
I _{OK}	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC}$ + 0.5 V	<u>[1]</u> _	±20	mA
lo	output current	$V_{\rm O}$ = –0.5 V to V_{CC} + 0.5 V	<u>[1]</u> -	±25	mA
I _{CC}	supply current		<u>[1]</u> _	50	mA
I _{GND}	ground current		<u>[1]</u> _	-50	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation		[2] _	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 and SC-74 packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74HC2G17-	Q100					
V _{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C
74HCT2G17	7-Q100					
V _{CC}	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	°C

11. Static characteristics

Table 7. Static characteristics for 74HC2G17

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.18	4.32	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.68	5.81	-	V

Dual non-inverting Schmitt trigger

Table 7. Static characteristics for 74HC2G17 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Uni
V _{OL}	LOW-level output voltage	$V_I = V_{T+} \text{ or } V_{T-}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μA
lcc	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 6.0 \text{ V}$	-	-	1.0	μΑ
CI	input capacitance		-	2.0	-	pF
T _{amb} = -40	0 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_0 = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	4.13	-	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.63	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+} \text{ or } V_{T-}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	-	0.33	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
lcc	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 6.0 \text{ V}$	-	-	10.0	μA
T _{amb} = -40	0 °C to +125 °C					
V _{он}	HIGH-level output voltage	$V_I = V_{T+} \text{ or } V_{T-}$				
		I_O = –20 $\mu\text{A};V_{CC}$ = 2.0 V	1.9	-	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ \text{V}$	4.4	-	-	V
		$I_O = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ \text{V}$	5.9	-	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_0 = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V

Dual non-inverting Schmitt trigger

Table 7. Static characteristics for 74HC2G17 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{T+} \text{ or } V_{T-}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
I _I	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 6.0 \text{ V}$	-	-	20.0	μΑ

Table 8. Static characteristics for 74HCT2G17

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25 °	С					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-} ; $V_{CC} = 4.5 \text{ V}$				
		I _O = -20 μA	4.4	4.5	-	V
		I _O = -4.0 mA	4.18	4.32	-	V
V _{OL}	LOW-level output voltage	V_{I} = V_{T+} or $V_{T-};V_{CC}$ = 4.5 V				
		I _O = -20 μA	-	0	0.1	V
		I _O = -4.0 mA	-	0.15	0.26	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±0.1	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	1.0	μΑ
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 \text{ V};$ $V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}; I_{O} = 0 \text{ A}$	-	-	300	μΑ
CI	input capacitance		-	2.0	-	pF
T _{amb} = -40	°C to +85 °C					
V _{OH}	HIGH-level output voltage	V_{I} = V_{T+} or $V_{T-};V_{CC}$ = 4.5 V				
		I _O = -20 μA	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}$	4.13	-	-	V
V _{OL}	LOW-level output voltage	V_{I} = V_{T+} or $V_{T-};V_{CC}$ = 4.5 V				
		I _O = -20 μA	-	-	0.1	V
		$I_{O} = -4.0 \text{ mA}$	-	-	0.33	V
l _l	input leakage current	$V_I = GND \text{ or } V_{CC}; V_{CC} = 5.5 \text{ V}$	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	10.0	μΑ
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 \text{ V};$ $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_{O} = 0 \text{ A}$	-	-	375	μΑ

Dual non-inverting Schmitt trigger

Table 8. Static characteristics for 74HCT2G17 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -40	°C to +125 °C					
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-} ; $V_{CC} = 4.5 \text{ V}$				
		$I_O = -20 \ \mu A$	4.4	-	-	V
		$I_{O} = -4.0 \text{ mA}$	3.7	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-} ; $V_{CC} = 4.5 \text{ V}$				
		I _O = -20 μA	-	-	0.1	V
		$I_{O} = -4.0 \text{ mA}$	-	-	0.4	V
l _l	input leakage current	V_{I} = GND or V_{CC} ; V_{CC} = 5.5 V	-	-	±1.0	μA
I _{CC}	supply current	$V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	20.0	μΑ
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 2.1 \text{ V};$ $V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}; I_{O} = 0 \text{ A}$	-	-	410	μΑ

12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions			25 °C		-40	0 °C to +1	25 °C	Unit
				Min	Тур	Мах	Min	Max (85 °C)	Max (125 °C)	
74HC2G1	7-Q100									
t _{pd}	propagation delay	nA to nY; see Figure 5	[1]							
		$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	36	115	-	140	175	ns
		V_{CC} = 4.5 V; C_{L} = 50 pF		-	12	22	-	27	34	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	10	18	-	22	28	ns
t _t	transition time	nY; see <u>Figure 5</u>	[2]							
		$V_{CC} = 2.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	20	75	-	95	110	ns
		V_{CC} = 4.5 V; C_{L} = 50 pF		-	7	15	-	19	22	ns
		$V_{CC} = 6.0 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	5	13	-	16	19	ns
C _{PD}	power dissipation capacitance	$V_I = GND$ to V_{CC}	[3]	-	10	-	-	-	-	pF

Dual non-inverting Schmitt trigger

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C			Unit	
				Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
74HCT26	17-Q100									
t _{pd} p	propagation delay	nA to nY; see Figure 5	[1]							
		V_{CC} = 4.5 V; C_{L} = 50 pF		-	21	29	-	36	45	ns
t _t	transition time	nY; see <u>Figure 5</u>	[2]							
		$V_{CC} = 4.5 \text{ V}; \text{ C}_{L} = 50 \text{ pF}$		-	6	15	-	19	22	ns
C _{PD}	power dissipation capacitance	V_{I} = GND to V_{CC} – 1.5 V	<u>[3]</u>	-	10	-	-	-	-	pF

Table 9. Dynamic characteristics ... continued

[1] t_{pd} is the same as t_{PLH} and t_{PHL}

- [2] t_t is the same as t_{TLH} and t_{THL}
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_0 = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

13. Waveforms

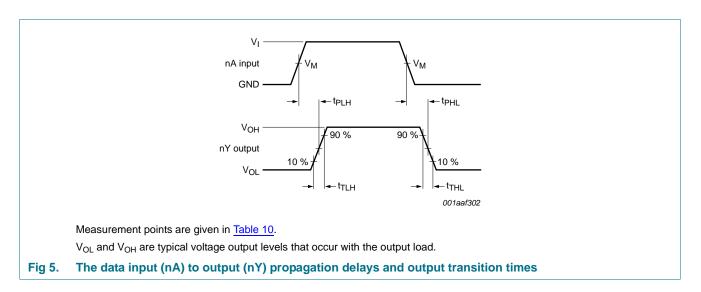


Table 10. Measurement points

Туре	Input			
	V _M	VI	t _r = t _f	V _M
74HC2G17-Q100	0.5V _{CC}	GND to V _{CC}	6.0 ns	0.5V _{CC}
74HCT2G17-Q100	1.3 V	GND to 3.0 V	6.0 ns	1.3 V

Dual non-inverting Schmitt trigger

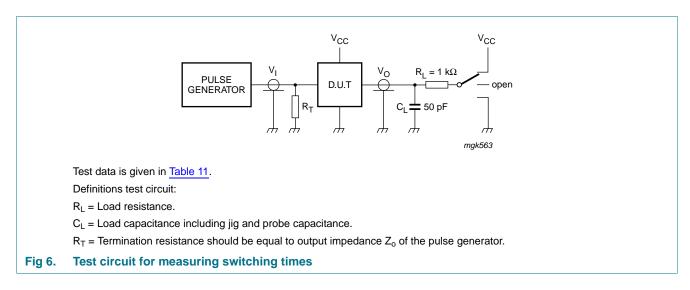


Table 11. Test data

Туре	Input	Test	
	VI	t _r , t _f	t _{PHL} , t _{PLH}
74HC2G17-Q100	GND to V _{CC}	6 ns	open
74HCT2G17-Q100	GND to 3.0 V	6 ns	open

14. Transfer characteristics

Table 12. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

Symbol	Parameter	Conditions		25 °C		-4	0 °C to +1	25 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
74HC2G	17-Q100		,						
V _{T+}	positive-going	see Figure 7, Figure 8							
	threshold voltage	$V_{CC} = 2.0 V$	1.00	1.18	1.50	1.00	1.50	1.50	V
		$V_{CC} = 4.5 V$	2.30	2.60	3.15	2.30	3.15	3.15	V
		$V_{CC} = 6.0 V$	3.00	3.46	4.20	3.00	4.20	4.20	V
	negative-going threshold voltage	see Figure 7, Figure 8							
		$V_{CC} = 2.0 V$	0.30	0.60	0.90	0.30	0.90	0.90	V
		$V_{CC} = 4.5 V$	1.13	1.47	2.00	1.13	2.00	2.00	V
		$V_{CC} = 6.0 V$	1.50	2.06	2.60	1.50	2.60	2.60	V
V _H	hysteresis voltage	V _{T+} – V _{T–} ; see <u>Figure 7,</u> <u>Figure 8</u> and <u>Figure 9</u>							
		$V_{CC} = 2.0 V$	0.30	0.60	1.00	0.30	1.00	1.00	V
		$V_{CC} = 4.5 V$	0.60	1.13	1.40	0.60	1.40	1.40	V
		$V_{CC} = 6.0 V$	0.80	1.40	1.70	0.80	1.70	1.70	V

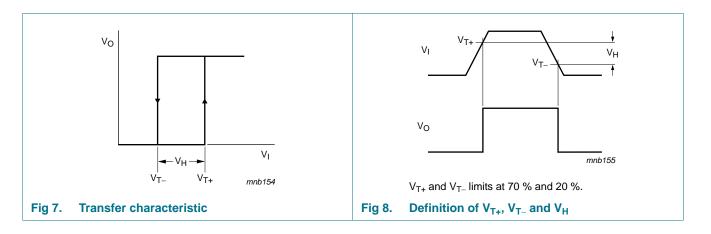
Dual non-inverting Schmitt trigger

Symbol	Parameter	Conditions		25 °C		–40 °C to +125 °C		25 °C	Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
74HCT20	G17-Q100		ľ						
V _{T+} positive-going		see Figure 7 and Figure 8							
th	threshold voltage	$V_{CC} = 4.5 V$	1.20	1.58	1.90	1.20	1.90	1.90	V
		$V_{CC} = 5.5 V$	1.40	1.78	2.10	1.40	2.10	2.10	V
V_{T-}	negative-going	see Figure 7 and Figure 8							
	threshold voltage	$V_{CC} = 4.5 V$	0.50	0.87	1.20	0.50	1.20	1.20	V
		$V_{CC} = 5.5 V$	0.60	1.11	1.40	0.60	1.40	1.40	V
V _H	hysteresis voltage	V _{T+} – V _{T-} ; see <u>Figure 7,</u> <u>Figure 8</u> and <u>Figure 10</u>							
		$V_{CC} = 4.5 V$	0.40	0.71	-	0.40	-	-	V
		$V_{CC} = 5.5 V$	0.40	0.67	-	0.40	-	-	V

Table 12. Transfer characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 6.

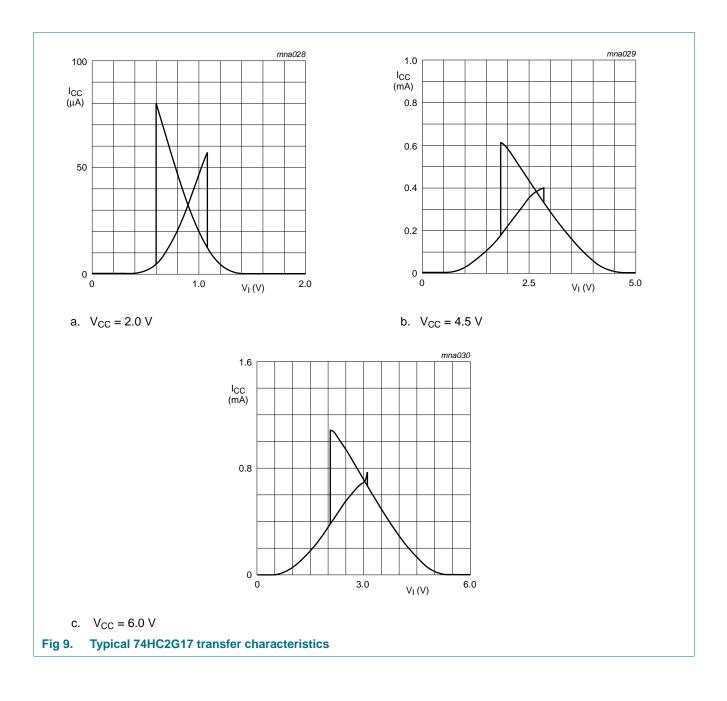
15. Waveforms transfer characteristics



NXP Semiconductors

74HC2G17-Q100; 74HCT2G17-Q100

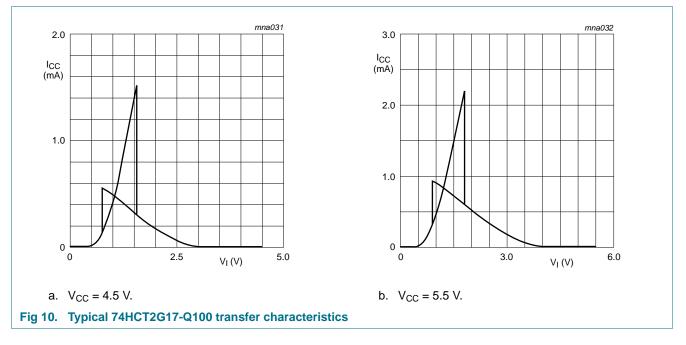
Dual non-inverting Schmitt trigger



NXP Semiconductors

74HC2G17-Q100; 74HCT2G17-Q100

Dual non-inverting Schmitt trigger



16. Application information

The slow input rise and fall times cause additional power dissipation which can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

 P_{add} = additional power dissipation (μ W);

 $f_i = input frequency (MHz);$

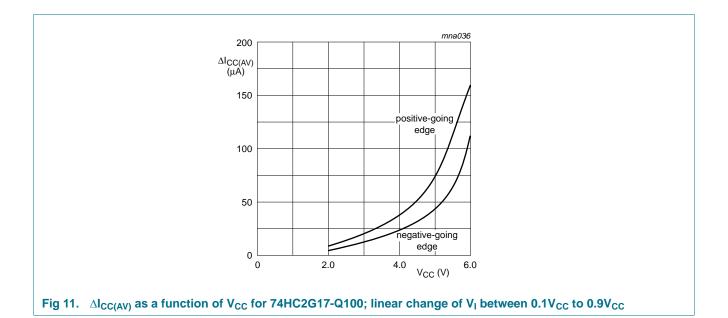
 t_r = input rise time (ns); 10 % to 90 %;

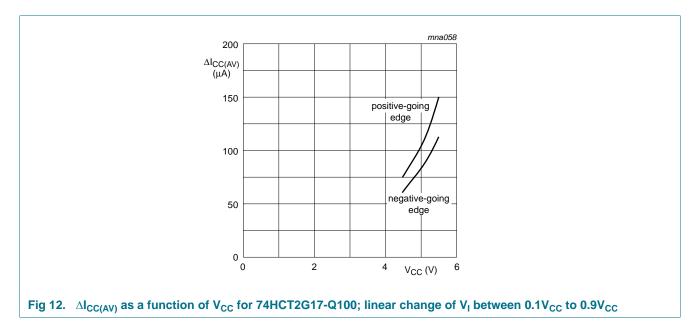
 t_f = input fall time (ns); 90 % to 10 %;

 $\Delta I_{CC(AV)}$ = average additional supply current (µA).

 $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 11 and Figure 12.

Dual non-inverting Schmitt trigger





Dual non-inverting Schmitt trigger

17. Package outline

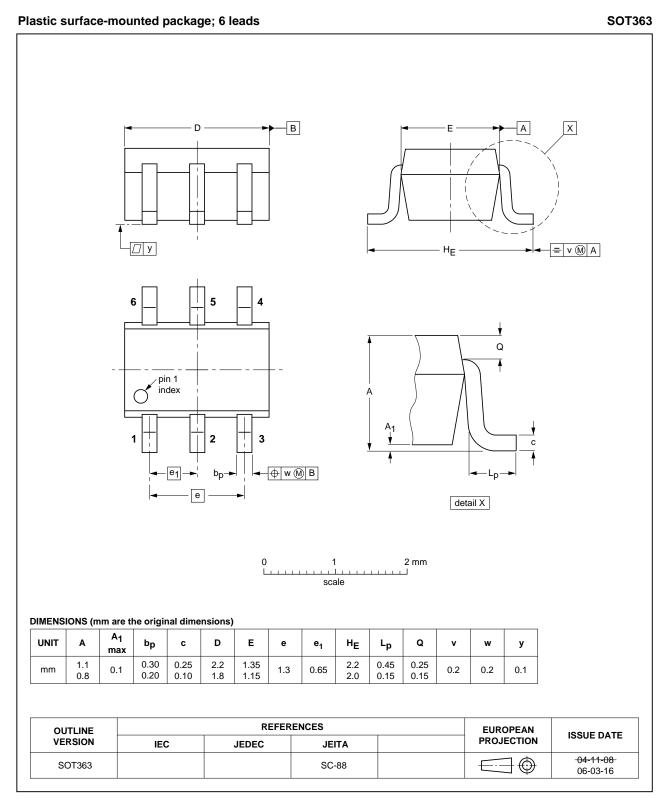


Fig 13. Package outline SOT363 (SC-88)

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Dual non-inverting Schmitt trigger

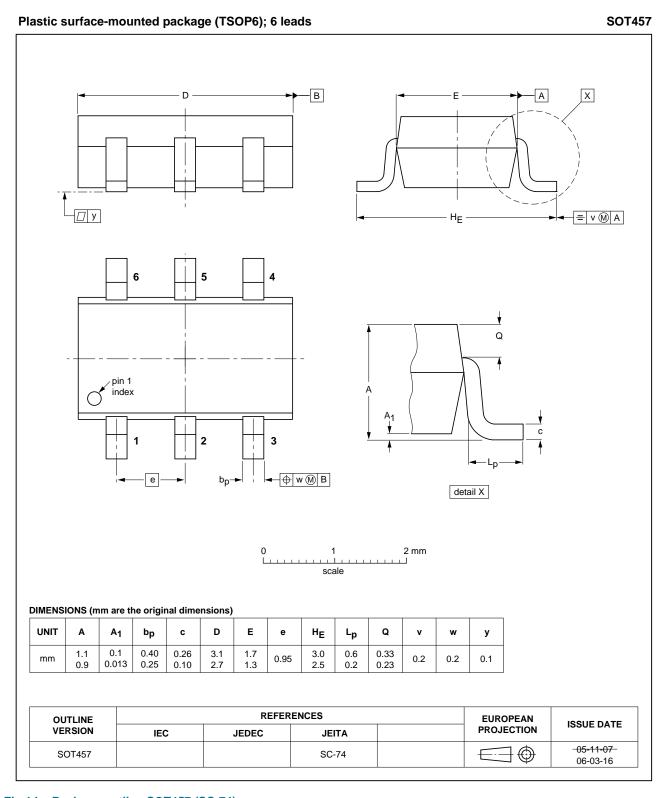


Fig 14. Package outline SOT457 (SC-74)

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18. Abbreviations

Table 13.	Abbreviations
Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
TTL	Transistor-Transistor Logic
HBM	Human Body Model
ESD	ElectroStatic Discharge
MM	Machine Model
DUT	Device Under Test
MIL	Military

19. Revision history

Table 14. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT2G17_Q100 v.1	20130522	Product data sheet	-	-

Dual non-inverting Schmitt trigger

20. Legal information

20.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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Dual non-inverting Schmitt trigger

22. Contents

General description 1
Features and benefits 1
Applications 1
Ordering information 2
Marking 2
Functional diagram 2
Pinning information 3
Pinning
Pin description 3
Functional description 3
Limiting values 4
Recommended operating conditions 4
Static characteristics 4
Dynamic characteristics 7
Waveforms 8
Transfer characteristics 9
Waveforms transfer characteristics 10
Application information
Package outline 14
Abbreviations 16
Revision history 16
Legal information 17
Data sheet status 17
Definitions 17
Disclaimers
Trademarks
Contact information 18
Contents 19

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